## EEE103/EEE121/EEE141 Problem Solutions

## Transistors as Switches and Amphfiers

- It is important to ensure that a transistor switch is driven on and off properly in order to minimise power dissipation within the switch. When on, one wants a small voltage across the switch so that Ion Von is small and when off one wants a small current through the switch (ideally zero) so that Ioff Vor is small. If the switch is only half switched on, the VI product dissipated within it is likely to destroy it.
  - (1)  $I_{ON} = \frac{50^{\circ}}{40^{\circ}n} = \frac{1.25 A}{40^{\circ}n}$ . (assumes VCESAT negligible).
  - (11) Worst case IB (re largest IB) occurs for smallest he.

$$I_{\text{Rmax}} = \frac{I_{\text{CON}}}{h_{\text{FEMIN}}}$$

$$= \frac{1.25A}{70} = \frac{17.86 \, \text{mA}}{1}$$

(IV) Power lost in transistor during "on" state is  $P_{D} = I_{CON} \cdot V_{CESAT} = 1.25A \times 0.25V$  = 313 mW

Q2 In their "on" state, Mosfets look like a resistance of Voson so the power dissipation is I Don Toson.

= 1.25 × 0.25 x = 390 mW.

[This assumes that the "on" menstance of the Mosfet does not significantly alter IDON le, that roson < Ri ; chearly true here]

Since the Mospets dissipate more energy as heat, they are less attractive than the BJT.

- Q3 (1) If s has been on for a long time.
  - (i)  $E = \frac{1}{2}LI^2 = \frac{1}{2} \times 0.1 \times 1.25A^2 = \frac{78 \text{ mJ}}{2}$ 
    - (11) D and R provide a path by which the moductor can maintain current continuity when the switch switches off. They do it in a way that defines the maximum off state voltage across the switch.
    - (111) ID = Icon = 1.25 A immediately after the switch opens.
    - (iv) The decay time constant is  $L_{RL} = \frac{100 \text{mH}}{40 \text{m}}$   $= \frac{2.5 \text{ m/s}}{100 \text{ m}}$
  - (v) Is will create a voltage across R with its positive end at D's cathode. This voltage, IDR, will add to the 50V supply. to give the switch off-state voltage.

    If S can cape with 200V, 50 + IDMAXR = 200 or R =  $\frac{200-50}{1.25} = \frac{150}{1.25} = \frac{120 \text{ J}}{1.25}$

(vi) If the switch switches 50 times per second, Energy loss per second, which aguals power is  $P = 78 \,\mathrm{mJ} \times 50 = 3.9 \,\mathrm{W}$ .

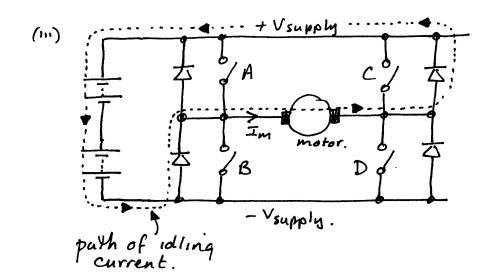
This power is shared between R and the 40x internal resistance of the load and since the same Is flows through both, power is proportional to R.

Thus  $P_R = 3.9 \text{ w} \times \frac{R}{40 + R} = 3.9 \times \frac{100}{140}$ 

= 2.8W

Note that the your part of the load will also dissipate energy in the "on" state - in this case at a ratie of 62.5W-so the energy stored in L contributes only a small increment to this for the conditions of the question

- 1) Switches A and D will cause clockwise motion when on.
  - (11) switches C and B will cause anti-clockwise motion when on.



$$\frac{Q5}{8.2MR} = \frac{20 - \sqrt{8E}}{8.2MR} = \frac{19.3}{8.2MR} = \frac{2.35\mu A}{8}$$

Icmin = 
$$I_8 h_{FEmin}$$
 = 2.35µA×100 = 235µA.  
 $V_{CE} = 20 - I_{CR}$   
=  $20 - 2mA = 75ku = 5v$  for  $h_{FE} = 850$   
=  $20 - 235µA = 7.5ku = 18.2v$  for  $h_{FE} = 100$ 

(111) The cct is a poor bias circuit because it fails to control Ic; instead it controls Is.

(iv) From the cct, 
$$V_{CE} = V_{CL} - I_{CR}L$$
, and using  $h_{FE} = I_{Cl}I_{8}$  this can be written  $V_{CE} = V_{CL} - h_{FE}I_{8}R_{L}$ .

The normalised change in he with temp is 0.590 ....

$$ie \frac{1}{h_{FE}} \cdot \frac{dh_{FE}}{dT} = \frac{0.5}{100}$$

If you have trouble with this, put it in terms of money. If someone was to pay you 0.5% of \$450 per week, how much would you get per week?]

dVce dVce dhe by differentiating (1)

$$V_E = V_B - V_{BE}$$

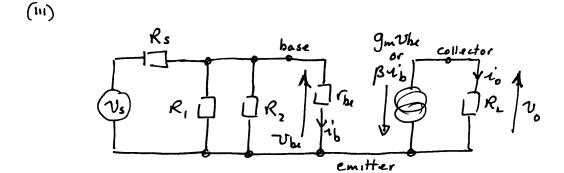
$$= 3.92 - 0.7 = 3.22 V$$

$$I_E \approx I_C = 3.22 V = 3.22 mA$$

$$I_E \approx I_c = \frac{3.22 \text{V}}{R_E} = \frac{3.22 \text{mA}}{2}$$

$$V_c = V_{cc} - I_c R_L = 20 - 3.22 \times 2.4 k \cdot 10^{-3}$$
  
=  $20 - 7.73 = 12.3 \text{ V}$ 

(ii) 
$$g_m = \frac{eI_c}{kT} = \frac{3.22mA}{.026 V} = \frac{0.124 A/V}{.026 V}$$
.  
 $f_{be} = \beta/g_m = \frac{500}{0.124} = \frac{4.04 k s_L}{.026 V}$ 



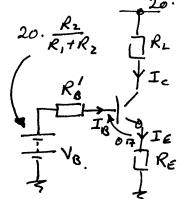
(iv) 
$$\frac{v_0}{v_s} = \frac{v_0}{v_{be}} \times \frac{v_{be}}{v_{s}}$$
  
 $\frac{v_0}{v_{be}} = -g_m R_L$  (Since  $u'_0 = -g_m v_{be} R_L$ ).  
 $\frac{v_{be}}{v_s} = \frac{R_1 ||R_2|| ||r_{be}||}{R_s + R_1 ||R_2|| ||r_{be}||} = \frac{3.58 kn}{10 kn + 3.58 lin} = 0.263$   
 $\frac{v_0}{v_s} = -g_m R_L \times 0.263 = \frac{78.3}{v_s}$ 

(V) follow the same general process as in Q5 pt (IV). Here the feedback makes the equations more cumbersome ....

First replace R, + Rz by a Therenin equiv (not essential but malces it a bit easier).

 $V_8 = I_8 R_8' + 0.7 + I_E R_E$ but  $I_E = I_8 + I_c$ 

:  $V_{B} = I_{B}R_{B}' + 0.7 + I_{B}R_{E} + I_{c}R_{E}$ =  $I_{B}(R_{B}' + R_{E}) + 0.7 + I_{c}R_{E}$ 



now Ic is the variable of interest in the question so eliminate IB using IB = Ic has

 $V_{B} = \frac{I_{c}}{h_{FE}} (R_{B}^{\prime} + R_{E}) + 0.7 + I_{c}R_{E}$ 

or Ic = (V8-0.7) hFE = 3.22 hFE = (RB'+ RE + hFE RE)

[one could say here RE+ here = here if he >> 1]

As in Q5 pt (iv)  $\frac{dIc}{dT} = \frac{dIc}{dh_{FE}} \cdot \frac{dh_{FE}}{dT} \cdot \cdots \cdot \text{from } ② \text{ in 5pt (iv)}.$ 

 $\frac{dI_c}{dh_{FE}} = \frac{\left(R_B' + R_E + h_{FE}R_E\right). 3.22 - R_E. 3.22 h_{FE}}{\left(R_B' + R_E + h_{FE}R_E\right)^2}$ 

note from 1) that (Ritrethfere) = (3.22hre)

So  $\frac{dI_c}{dh_{RE}} = \frac{3.22 (R_B' + R_E) I_c^2}{(3.22 h_{RE})^2}$ =  $3.22 (R_B' + R_E) 3.21_x^2$ 

 $= \frac{3.22 (R_B + R_E) 3.22 \times 10^{-6}}{3.22 \times .450^{2}}$ 

 $\frac{dI_{c}}{dT} = \frac{3.22(R_{8}'+R_{E})\times10^{-6}}{450\%} \cdot \frac{450\times0.5}{100} = \frac{1.16\,\mu\text{A}/\text{o}\text{C}}{100}$ 

[This gives a Vc dependency of -2.78 mv/oc]

Q7 (1) you need to find two equations with IF and Ic as unknowns ...

$$24 = (I_c + I_F)R_L + I_F(R_1 + R_2) + I_FR_3$$
  
or  $24 = I_cR_L + I_F(R_L + R_1 + R_2 + R_3)$ 

and 
$$I_F R_3 = 0.7 + I_C R_E$$
 (Yhis assumes  $I_E \approx I_C$ ).

eliminating Ir from () + 2 ...

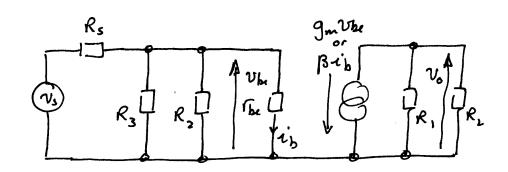
or 24' =  $I_{c \times 10 h N} + 0.7 \times 4.467 + I_{c \times} 2.7 \times 10^3 \times 4.467$ . =  $I_{c} (10 h N + 12.06 h N) + 3.13$ .

or 
$$I_c = \frac{20.87}{22.06 \, \text{km}} = \frac{946 \, \text{mA}}{2}$$

$$V_c = 24 - (I_{c+}I_{F})R_L = 24 - 1.054 \text{ mAx lok}$$
  
= 13.5 V

(11) 
$$g_m = \frac{e^{-Tc}}{1cT} = \frac{946 \times 10^{-6}}{.026} = \frac{36.4 \text{ mA/V}}{.026} (0.20364 \text{ A/V})$$
  
 $r_{be} = r_{c} = \frac{500}{.0364} = \frac{13.7 \text{ k.s.}}{.0364}$ 

(111)



(iv) if 
$$R_s=0$$
,  $V_s=V_{be}$  and gain is
$$\frac{V_0}{V_s}=\frac{V_0}{V_{be}}=-g_m R_L ||R_F|=\frac{-300}{100}$$

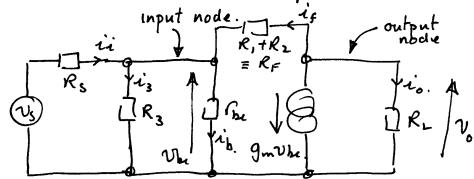
If 
$$R_s = 10 \text{ km}$$
 ....

 $\frac{V_6}{V_s} = \frac{V_0}{V_{be}}$ ,  $\frac{V_{be}}{V_s}$ .

 $\frac{V_{be}}{V_s} = \frac{R_3 || R_2 || || V_{be}}{R_s + R_3 || R_2 || || V_{be}} = \frac{7.84 \text{ km}}{17.84 \text{ km}} = 0.439$ .

 $\frac{V_0}{V_s} = -300 = 0.439 = -132$ 

(v) if C3 removed the cct changes to



Sum currents at output node ....

$$i_{f} + i_{0} + g_{m} v_{be} = 0$$
or  $v_{0} - v_{be} + v_{0} + g_{m} v_{be} = 0$  ———(1)

Sum currents at input node....  $i_i + i_f = i_3 + i_b$ 

or 
$$\frac{v_s - v_{be}}{R_s} + \frac{v_o - v_{be}}{R_f} = \frac{v_{be}}{R_3} + \frac{v_{be}}{v_{be}}$$
 (2)

· Whe can be reliminated from O + @ to give

$$\frac{v_o}{v_s} = \frac{\frac{1}{R_s}}{\left[\frac{R_L + R_F}{R_L (1 - g_m R_F)} \cdot \left(\frac{1}{R_s} + \frac{1}{R_F} + \frac{1}{R_3} + \frac{1}{r_{he}}\right) - \frac{1}{R_F}\right]}$$

$$= -8.85$$

The big reduction of gain here occurs because there is now feedback between collector + base (via RF) that operates on the signal.